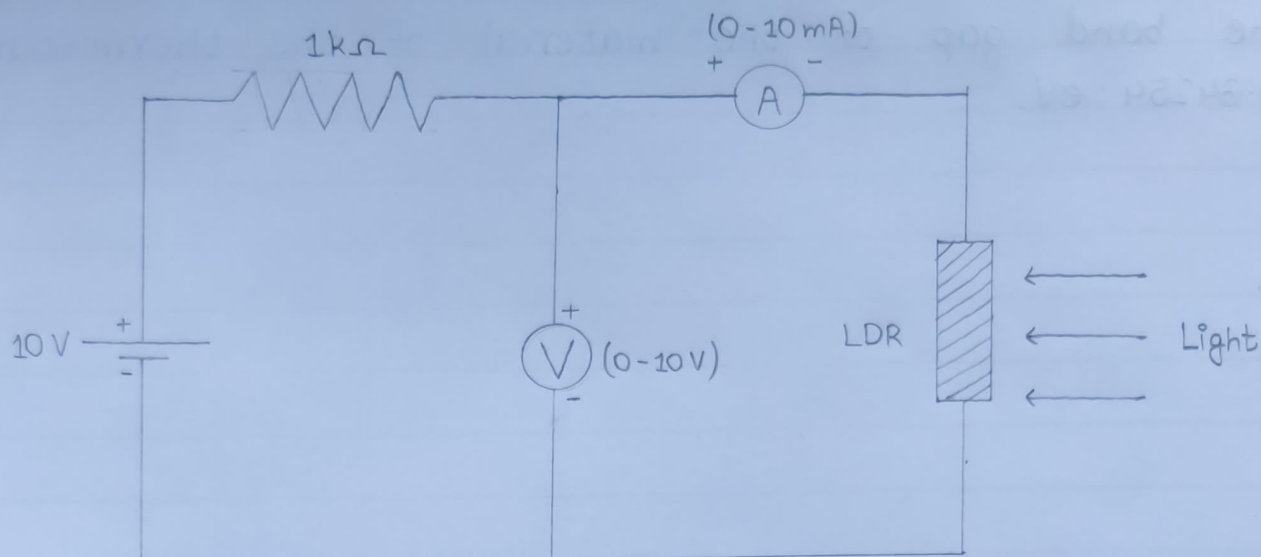


DIAGRAM \Rightarrow



TO DETERMINE THE RESISTANCES OF LDR AT DIFFERENT DISTANCES \Rightarrow

Sr. No.	Distance	Voltmeter Reading	Ammeter Reading	R_x
	cm	(V) volt	(I) mA	$k\Omega$
1.	A = 15cm	1	4	0.250
2.		2	6	0.333
3.		3	10	0.300
4.		4	12	0.333
5.		5	14	0.357
MEAN \Rightarrow				0.314
1.	B = 10cm	1	8	0.125
2.		2	12	0.166
3.		3	16	0.187

TO STUDY V-I CHARACTERISTICS OF A LIGHT DEPENDENT RESISTOR (LDR).

AIM \Rightarrow

To measure the photoconductive nature and the dark resistance of the given light dependent resistor (LDR) and to plot the characteristics of the LDR.

APPARATUS REQUIRED \Rightarrow

LDR, Resistor ($1k\Omega$), ammeter (0-10 mA), voltmeter (0-10V), light source, regulated power supply.

FORMULA \Rightarrow

By Ohm's law, $V = IR$ or $R = \frac{V}{I}$ ohm

where, 'R' is the resistance of the LDR (i.e.) the resistance when the LDR is closed. 'V' and 'I' represents the corresponding voltage and current respectively.

PRINCIPLE \Rightarrow

The photoconductive device is based on the decrease in the resistance of certain semiconductor materials when they are exposed to both infrared and visible radiation.

The photoconductivity is the result of carrier excitation due to light absorption and the figure of merit depends on the light absorption.

4.		4	20	0.200
5.		5	24	0.208
MEAN \Rightarrow				0.177

1.	C = 5cm	1	10	0.100
2.		2	14	0.142
3.		3	18	0.166
4.		4	23	0.173
5.		5	28	0.178
			MEAN \Rightarrow	0.151

OBSERVATIONS \Rightarrow

- 1> Voltmeter reading when the LDR is closed = 5V
- 2> Ammeter reading when the LDR is closed = 14 mA.
- 3> Dark Resistance (R) = $\frac{V}{I} = \frac{5}{14} = 0.357 \text{ k}\Omega$.

CALCULATIONS \Rightarrow

1> $V = 1V$; $I = 4 \text{ mA}$
 $\therefore R = \frac{V}{I} = \frac{1}{4} = 0.250 \text{ k}\Omega$

2> $V = 2V$; $I = 6 \text{ mA}$
 $\therefore R = \frac{V}{I} = \frac{2}{6} = 0.333 \text{ k}\Omega$

3> $V = 3V$; $I = 10 \text{ mA}$
 $\therefore R = \frac{V}{I} = \frac{3}{10} = 0.300 \text{ k}\Omega$

4> $V = 1V$; $I = 8 \text{ mA}$
 $\therefore R = \frac{V}{I} = \frac{1}{8} = 0.125 \text{ k}\Omega$

efficiency. The increase in conductivity is due to an increase in the number of mobile charge carriers in the material.

5) $V = 2V$; $I = 12mA$
 $\therefore R = \frac{V}{I} = \frac{2}{12} = 0.166 k\Omega$

7) $V = 1V$; $I = 10mA$
 $\therefore R = \frac{V}{I} = \frac{1}{10} = 0.100 k\Omega$

9) $V = 3V$; $I = 18mA$
 $\therefore R = \frac{V}{I} = \frac{3}{18} = 0.166 k\Omega$

6) $V = 3V$; $I = 16mA$
 $\therefore R = \frac{V}{I} = \frac{3}{16} = 0.187 k\Omega$

8) $V = 2V$; $I = 14mA$
 $\therefore R = \frac{V}{I} = \frac{2}{14} = 0.142 k\Omega$

RESULT \Rightarrow

- 1) The characteristics of LDR were studied and plotted.
- 2) The dark resistance of the given LDR = $0.357 \text{ k}\Omega$.

Scale:

On x -axis \Rightarrow

1cm = 1cm (distance)

On y -axis \Rightarrow

1cm = 0.025 kN

